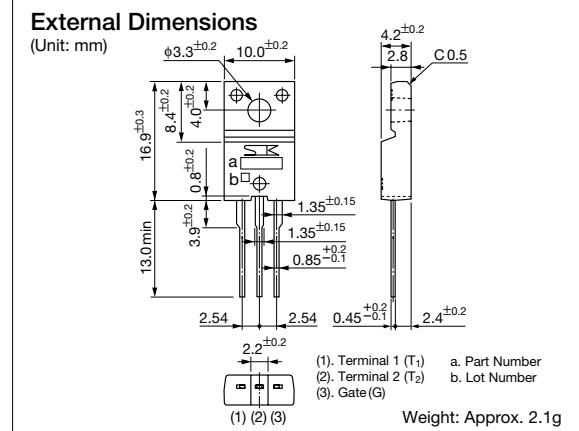


TO-220F 8A Triac

TM841S-L, TM861S-L

■ Features

- Repetitive peak off-state voltage: $V_{DRM}=400, 600V$
- RMS on-state current: $I_{T(RMS)}=8A$
- Gate trigger current: $I_{GT}=30mA$ max (MODE I, II, III)
- Isolation voltage: $V_{ISO}=1500V$ (50Hz Sine wave, RMS)
- UL approved type available



■ Absolute Maximum Ratings

Parameter	Symbol	Ratings		Unit	Conditions
		TM841S-L	TM861S-L		
Repetitive peak off-state voltage	V_{DRM}	400	600	V	
RMS on-state current	$I_{T(RMS)}$	8.0		A	Conduction angle 360°, $T_c=90^\circ C$
Surge on-state current	I_{TSM}	80		A	50Hz full-cycle sinewave, Peak value, Non-repetitive, $T_j=125^\circ C$
Peak gate voltage	V_{GM}	10		V	
Peak gate current	I_{GM}	2		A	
Peak gate power loss	P_{GM}	5		W	
Average gate power loss	$P_{G(AV)}$	0.5		W	
Junction temperature	T_j	-40 to +125		°C	
Storage temperature	T_{stg}	-40 to +125		°C	
Isolation voltage	V_{ISO}	1500		Vrms	50Hz Sine wave, RMS, Terminal to Case, 1 min.

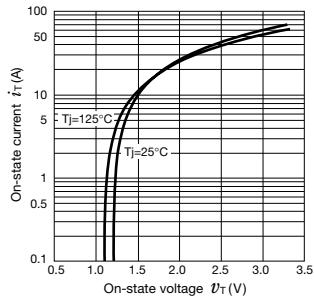
■ Electrical Characteristics

($T_j=25^\circ C$, unless otherwise specified)

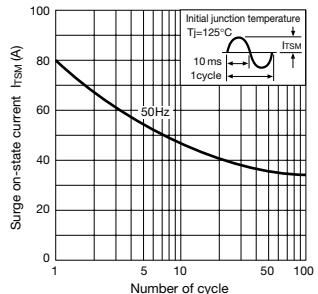
Parameter	Symbol	Ratings			Unit	Conditions
		min	typ	max		
Off-state current	I_{DRM}		0.3	2.0	mA	$V_D=V_{DRM}$, $R_{GK}=\infty$, $T_j=125^\circ C$
				0.1		$V_D=V_{DRM}$, $R_{GK}=\infty$, $T_j=25^\circ C$
On-state voltage	V_{TM}			1.6	V	Pulse test, $I_{TM}=10A$
Gate trigger voltage	V_{GT}	I	0.8	2.0	V	$V_D=6V$, $R_L=10\Omega$, $T_C=25^\circ C$
		II	0.7	2.0		
		III	0.8	2.0		
		IV	0.9			
Gate trigger current	I_{GT}	I	8	30	mA	$V_D=6V$, $R_L=10\Omega$, $T_C=25^\circ C$
		II	10	30		
		III	12	30		
		IV	30			
Gate non-trigger voltage	V_{GD}	0.2			V	$V_D=1/2 \times V_{DRM}$, $T_j=125^\circ C$
Holding current	I_H		12		mA	$V_D=6V$
Thermal resistance	R_{th}			3.6	°C/W	Junction to case

TM841S-L, TM861S-L

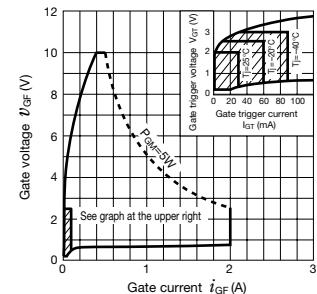
$V_T - i_T$ Characteristics (max)



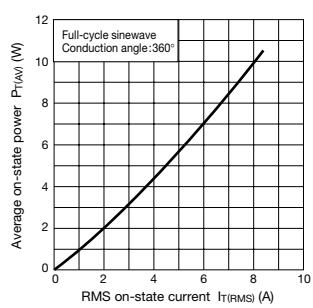
I_{TSM} Ratings



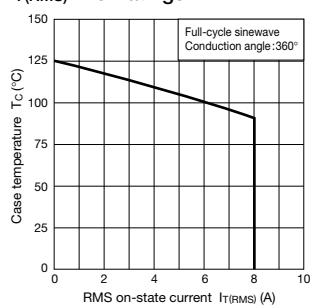
Gate Characteristics



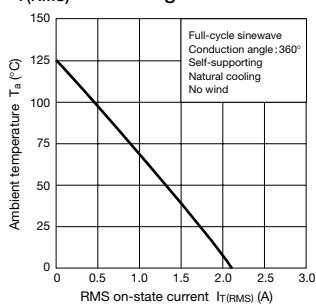
I_{T(RMS)} – P_{T(AV)} Characteristics



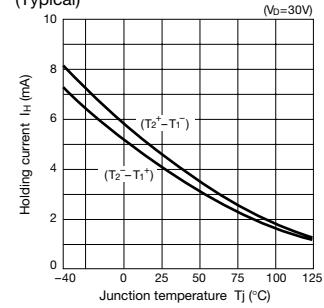
I_{T(RMS)} – T_c Ratings



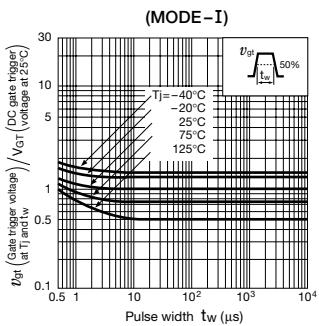
I_{T(RMS)} – T_a Ratings



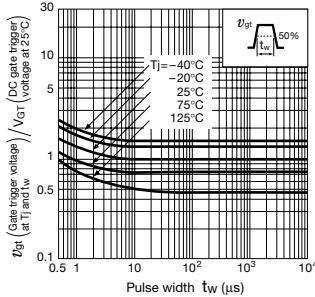
I_H temperature Characteristics (Typical)



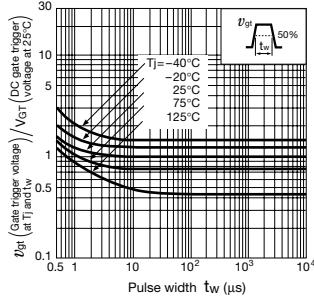
Pulse trigger temperature Characteristics V_{gt} (Typical)



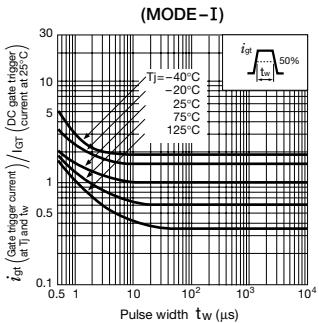
(MODE-II)



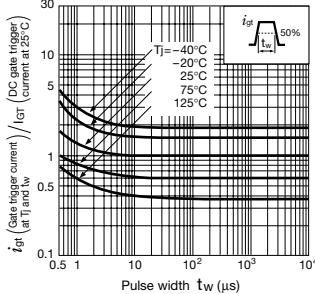
(MODE-III)



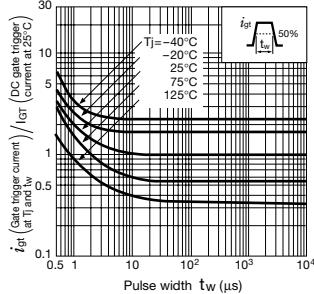
Pulse trigger temperature Characteristics i_{gt} (Typical)



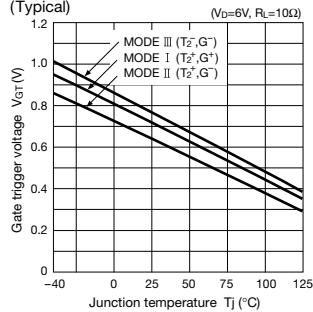
(MODE-II)



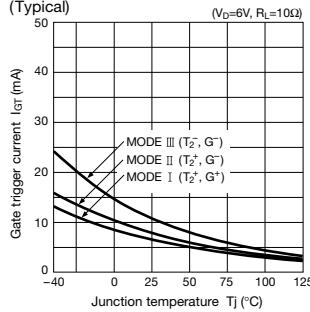
(MODE-III)



V_{GT} temperature characteristics (Typical)



I_{GT} temperature characteristics (Typical)



Transient thermal resistance Characteristics

